

Comment on "Cyclotron resonance study of the electron and hole velocity in graphene monolayers"

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In this comment it is pointed out that the electron velocity of the same order as observed in graphene had been measured in GaAs submicron devices long ago. Particle- antiparticle asymmetry related with electron and hole effective masses in graphene seems puzzling as hole in a condensed matter system cannot be treated as anti-electron. It is argued that there should be a universal electrodynamics for QHE and superconductivity. In this context attention is drawn to the new approach based on massless electron and the interpretation that magnetic field represents angular momentum of the photon fluid. Measurement of electron velocity in graphene and GaAs in parallel is suggested for testing the massless electrodynamics.

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Sciencewatch (CERN Courier May 2007) highlighted the reported observation of QHE in graphene at room temperature. A phrase 'the fact that its electrons act in many ways like massless Dirac fermions' attracted my attention as I thought massless electron model proposed more than two decades ago, and comprehensively discussed in a monograph [1] may have found an experimental validation in graphene. A careful reading of the paper [2] shows that 'exceptionally high electron velocities' of the order of 1.117×10^8 cm/sec in graphene are, in fact, in the range observed in GaAs ballistic transport and velocity overshoot [3]. The concluding remark in [2] that the band structure of monolayer graphene is not well understood at present is quite reasonable. However the one on particle-antiparticle asymmetry is puzzling. Note that effective masses of electron and hole differ considerably in general; a hole in condensed matter system cannot be treated as an antiparticle of electron.

Though it is well known, perhaps it is useful to remind ourselves that Dirac in his famous work first identified antiparticle of electron to be proton-the only known positively charged elementary particle at that time. Weyl- a mathematician argued that symmetry on mathematical grounds demanded the mass of antiparticle equal to that of electron-later discovered as positron. Secondly the linear dispersion relation by itself, the approximate relation derived by Wallace for graphite, does not mean that hole could be treated as antiparticle. A massive (complex) Klein-Gordon field does not have linear relation between energy and momentum yet it has antiparticle, and photon has a linear relation yet there is no antiphoton (in the standard QFT).

In a more general context I would like to raise the following question: Is there a universal electrodynamics for QHE and superconductivity? First we note an important fact: quantized Hall resistance and magnetic flux quantum involve only fundamental constants (c , h , and e) and do not depend on the material properties or size of the samples. There exist compelling arguments discussed in detail in Sec. 9.2 of [1] indicating a universal electrodynamics

assuming massless electron and the interpretation that magnetic field is angular momentum flux of photon fluid. The measurement of electron velocity in superconductor and QHE device has been advocated in the book. That the problem of Cooper pair mass is nontrivial has been underscored by Mishonov [5] quoting de Gennes remark from Tinkham's book and Ginzburg's private communication. Amongst three characteristics (zero resistance, Meissner effect, and flux quantization) the explanation of zero resistance in BCS theory seems unsatisfactory. Feynman says [5] : "There is no resistance because all the electrons are collectively in the same state. In the ordinary flow of current you knock one electron or the other out of the regular flow, gradually deteriorating the general momentum. But here to get one electron away from what all the others are doing is very hard because of the tendency of all Bose particles to go in the same state. A current once started, just keeps on going forever." This is hardly an explanation, further persistent current is not quite the same as zero resistance. Weinberg [6] seems to have addressed the problem better- he remarks that the absence of resistance (other than that in closed rings for persistent current) can be understood considering time-dependent effects. Relating the voltage with the time derivative of a postulated Goldstone boson and defining a suitable Hamiltonian of the system he offers an explanation for zero resistance. The role of Cooper pairs, however remains obscure.

In a new approach field-free filamentary tubular structures in condensed matter system have been envisaged in which electrons move with the velocity of light [1]. Few collisions could result in quantized average drift velocity. This idea has been used to understand QHE and superconducting electrodynamics in [1]. A simple model for the ballistic transport [7] found remarkable support in new experiments at the IBM as noted by Heiblum [8] : "... new experiments, not yet published, show that ballistic transport through GaAs regions wider than previously reported (about 800 Å wide), result with... . These results are qualitatively in agreement with Tiwari's com-

ment”.

Recall that the eigenvalue of velocity operator in Dirac's theory is equal to $\pm c$; localizing electron wavepacket in a region smaller than electron's Compton wavelength leads to a mixing of negative and positive frequency states- the zitterbewegung of Schroedinger. Point electron theory of Dirac conflicts with the proposed extended structure [1, 9] and electron motion with light velocity is considered unphysical. In our model electron is an extended spatio-temporal 2+1 dimensional object, and has velocity in field-free region (or rather intrinsic) equal to c normal to the 2-spatial plane. Inertia is interpreted as a consequence of collisions or viscosity of the space, see modified Schroedinger equation derived using

this idea in PLA (1988) [9].

Obviously testing the radical idea of massless electron would have far reaching implications on fundamental physics. I suggest time-of-flight technique used in GaAs [10] be explored for graphene. It seems InAs semiconductor and Nb superconductor have transparent interface i.e. no Schottky barrier [11]. In that case long superconductor could be used to investigate the velocity of electron/Cooper pairs. In conclusion, studies on electron transport in GaAs and graphene carried out in parallel might give useful new physics. For GaAs properties we refer to [12].

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- [1] S. C. Tiwari, Rebirth of the Electron: Electromagnetism - An unorthodox new approach to fundamental problems in physics, IONP Studies in Natural Philosophy Vol. 2, published at <http://www.lulu.com/content/439658> .
 - [2] R. S. Deacon et al, arXiv: 0704.0410 v2 [cond-mat.mes-hall].
 - [3] M. Heiblum et al, Direct observation of ballistic transport in GaAs, Phys. Rev. Lett. 55, 2200 (1985).
 - [4] T. M. Mishonov, How to measure the Cooper pair mass using plasmons in low dimensional superconducting structures, ICTP Preprint IC/90/123 (1990).
 - [5] R. P. Feynman, The Feynman Lectures on Physics Vol. 3 (Addison-Wesley 1965) Ch. 21 p. 21-8.
 - [6] S. Weinberg, The Quantum Theory of Fields, Vol. II (C.U.P. 1996) pp332-352.
 - [7] S. C. Tiwari, Nonequilibrium transport in submicron GaAs devices, Int. J. Electronics, 62, 27 (1987).
 - [8] M. Heiblum, Unpublished Note (1986).
 - [9] S. C. Tiwari, The nature of electronic charge, Found. Phys. Lett. 19, 51 (2006) also arXiv: physics/0408053; Relativity, entanglement and the physical reality of the photon, J. Optics B:Semiclass. and Quantum 4, S39 (2002); Derivation of the Hamiltonian form of the Klein-Gordon equation from the Schroedinger-Furth quantum diffusion theory: comments, Phys. Lett. A 133, 279 (1988); and arXiv: physics/0406136.
 - [10] J. G. Ruch and G. S. Kino, Transport properties of GaAs, Phys. Rev. 174, 921 (1968).
 - [11] A. Dimoulas et al, Phys. Rev. Lett 74, 602 (1995)
 - [12] Gallium Arsenide Materials, Devices and Circuits. Ed. by M. J. Howes and D. V. Morgan (John Wiley 1985).